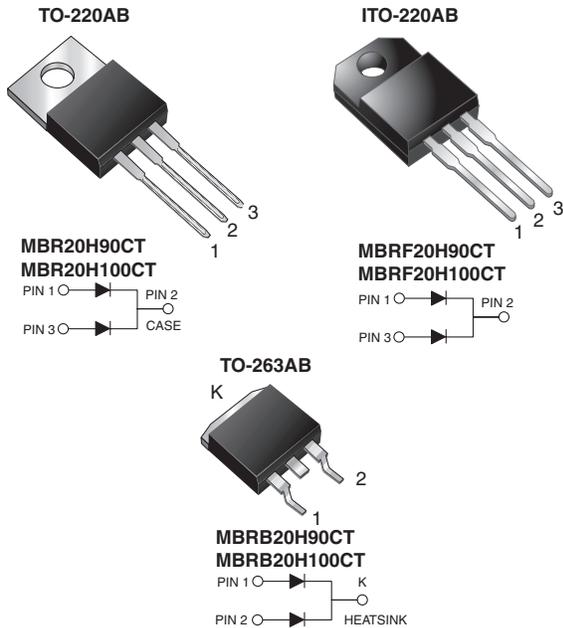


## Dual Common-Cathode High-Voltage Schottky Rectifier

High Barrier Technology for Improved High Temperature Performance



### FEATURES

- Guardring for overvoltage protection
- Lower power losses, high efficiency
- Low forward voltage drop
- Low leakage current
- High forward surge capability
- High frequency operation
- Meets MSL level 1, per J-STD-020, LF maximum peak of 245 °C (for TO-263AB package)
- Solder dip 260 °C, 40 s (for TO-220AB and ITO-220AB package)
- Component in accordance to RoHS 2002/95/EC and WEEE 2002/96/EC



**RoHS**  
COMPLIANT

### TYPICAL APPLICATIONS

For use in high frequency rectifier of switching mode power supplies, freewheeling diodes, dc-to-dc converters or polarity protection application.

### MECHANICAL DATA

**Case:** TO-220AB, ITO-220AB, TO-263AB

Epoxy meets UL 94V-0 flammability rating

**Terminals:** Matte tin plated leads, solderable per J-STD-002 and JESD22-B102

E3 suffix for consumer grade, meets JESD 201 class 1A whisker test, HE3 suffix for high reliability grade (AEC Q101 qualified), meets JESD 201 class 2 whisker test

**Polarity:** As marked

**Mounting Torque:** 10 in-lbs maximum

### PRIMARY CHARACTERISTICS

|             |             |
|-------------|-------------|
| $I_{F(AV)}$ | 10 A x 2    |
| $V_{RRM}$   | 90 V, 100 V |
| $I_{FSM}$   | 250 A       |
| $I_R$       | 4.5 $\mu$ A |
| $V_F$       | 0.64 V      |
| $T_J$ max.  | 175 °C      |

### MAXIMUM RATINGS ( $T_A = 25$ °C unless otherwise noted)

| PARAMETER   | SYMBOL         | MBR20H90CT    | MBR20H100CT | UNIT       |
|---|----------------|---------------|-------------|------------|
| Maximum repetitive peak reverse voltage   | $V_{RRM}$      | 90            | 100         | V          |
| Working peak reverse voltage  | $V_{RWM}$      | 90            | 100         | V          |
| Maximum DC blocking voltage   | $V_{DC}$       | 90            | 100         | V          |
| Maximum average forward rectified current<br>total device<br>per diode                          | $I_{F(AV)}$    | 20<br>10      |             | A          |
| Peak forward surge current 8.3 ms single half sine-wave<br>superimposed on rated load per diode | $I_{FSM}$      | 250           |             | A          |
| Peak repetitive reverse current per diode at $t_p = 2$ $\mu$ s, 1 kHz                           | $I_{RRM}$      | 1.0           |             | A          |
| Voltage rate of change (rated $V_R$ )   | dV/dt          | 10 000        |             | V/ $\mu$ s |
| Operating junction and storage temperature range  | $T_J, T_{STG}$ | - 65 to + 175 |             | °C         |
| Isolation voltage (ITO-220AB only)<br>from terminal to heatsink $t = 1$ min                     | $V_{AC}$       | 1500          |             | V          |

# MBR(F,B)20H90CT & MBR(F,B)20H100CT

Vishay General Semiconductor



| ELECTRICAL CHARACTERISTICS ( $T_A = 25\text{ }^\circ\text{C}$ unless otherwise noted) |                     |   |        |            |                     |
|---|---------------------|---|--------|------------|---------------------|
| PARAMETER   | TEST CONDITIONS     |   | SYMBOL | VALUE      | UNIT                |
| Maximum instantaneous forward voltage per diode <sup>(1)</sup>                        | $I_F = 10\text{ A}$ | $T_C = 25\text{ }^\circ\text{C}$                                      | $V_F$  | 0.77       | V                   |
|   | $I_F = 10\text{ A}$ | $T_C = 125\text{ }^\circ\text{C}$                                     |        | 0.64       |                     |
|   | $I_F = 20\text{ A}$ | $T_C = 25\text{ }^\circ\text{C}$                                      |        | 0.88       |                     |
|   | $I_F = 20\text{ A}$ | $T_C = 125\text{ }^\circ\text{C}$                                     |        | 0.73       |                     |
| Maximum reverse current per diode at working peak reverse voltage                     |                     | $T_J = 25\text{ }^\circ\text{C}$<br>$T_J = 125\text{ }^\circ\text{C}$ | $I_R$  | 4.5<br>6.0 | $\mu\text{A}$<br>mA |

**Note:**

(1) Pulse test: 300  $\mu\text{s}$  pulse width, 1 % duty cycle

| THERMAL CHARACTERISTICS ( $T_A = 25\text{ }^\circ\text{C}$ unless otherwise noted) |                 |     |      |      |                    |
|--|-----------------|-----|------|------|--------------------|
| PARAMETER  | SYMBOL          | MBR | MBRF | MBRB | UNIT               |
| Typical thermal resistance per diode   | $R_{\theta JC}$ | 2.0 | 5.8  | 2.0  | $^\circ\text{C/W}$ |

| ORDERING INFORMATION (Example) |                                   |                 |              |               |               |
|--------------------------------|-----------------------------------|-----------------|--------------|---------------|---------------|
| PACKAGE                        | PREFERRED P/N                     | UNIT WEIGHT (g) | PACKAGE CODE | BASE QUANTITY | DELIVERY MODE |
| TO-220AB                       | MBR20H100CT-E3/45                 | 1.85            | 45           | 50/tube       | Tube          |
| ITO-220AB                      | MBRF20H100CT-E3/45                | 1.99            | 45           | 50/tube       | Tube          |
| TO-263AB                       | MBRB20H100CT-E3/45                | 1.35            | 45           | 50/tube       | Tube          |
| TO-263AB                       | MBRB20H100CT-E3/81                | 1.35            | 81           | 800/reel      | Tape reel     |
| TO-220AB                       | MBR20H100CTHE3/45 <sup>(1)</sup>  | 1.85            | 45           | 50/tube       | Tube          |
| ITO-220AB                      | MBRF20H100CTHE3/45 <sup>(1)</sup> | 1.99            | 45           | 50/tube       | Tube          |
| TO-263AB                       | MBRB20H100CTHE3/45 <sup>(1)</sup> | 1.35            | 45           | 50/tube       | Tube          |
| TO-263AB                       | MBRB20H100CTHE3/81 <sup>(1)</sup> | 1.35            | 81           | 800/reel      | Tape reel     |

**Note:**

(1) Automotive grade AEC Q101 qualified

## RATINGS AND CHARACTERISTICS CURVES

( $T_A = 25\text{ }^\circ\text{C}$  unless otherwise noted)

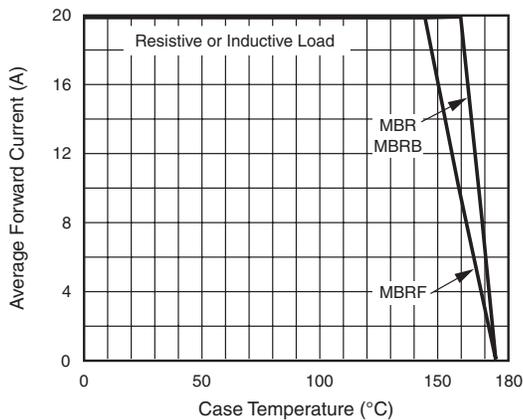


Figure 1. Forward Current Derating Curve

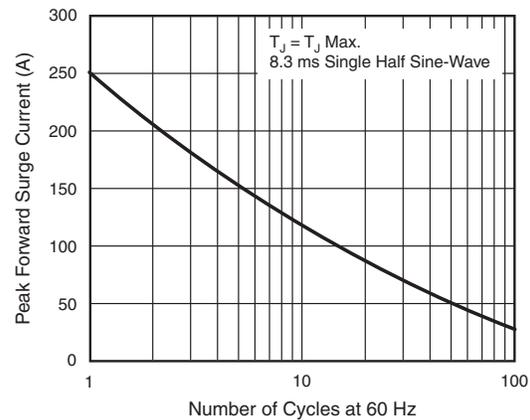


Figure 2. Maximum Non-Repetitive Peak Forward Surge Current Per Diode

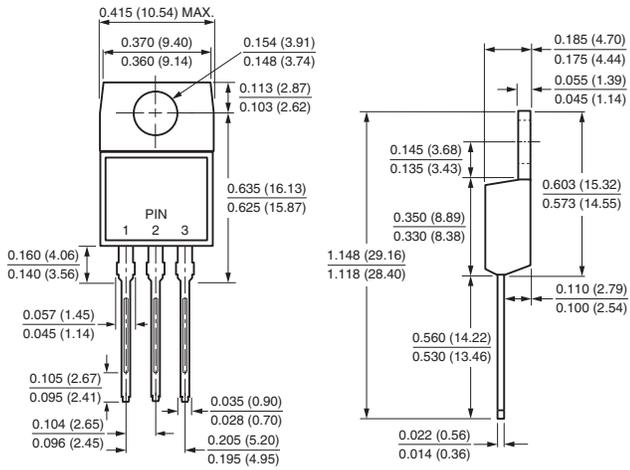
# MBR(F,B)20H90CT & MBR(F,B)20H100CT

Vishay General Semiconductor

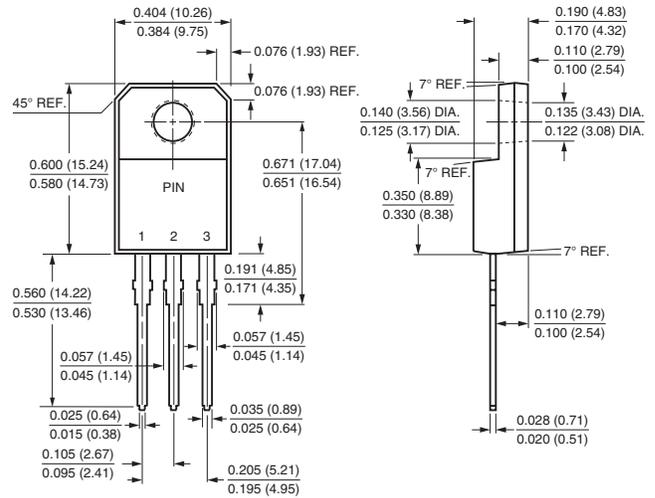


## PACKAGE OUTLINE DIMENSIONS in inches (millimeters)

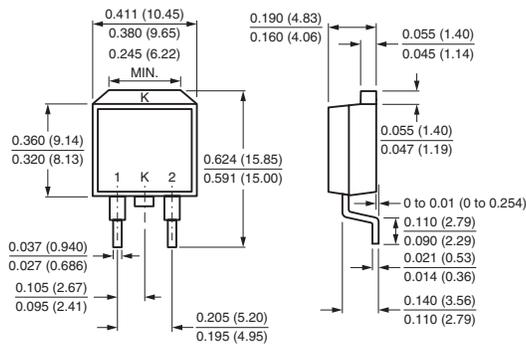
**TO-220AB**



**ITO-220AB**



**TO-263AB**



**Mounting Pad Layout**

